NSN 5961-01-354-2701

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-354-2701 **Inclosure Material:** Plastic and metal **Overall Length:** 2.030 inches **Overall Height:** Between 0.755 inches and 0.815 inches Overall Width: Between 0.970 inches and 1.030 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Component Name And Quantity:** 6 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 1.1 forward voltage, dc all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 09344-pc72266 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 12 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No